

**DEVICE  
ENGINEERING  
INCORPORATED**

385 East Alamo Drive  
Chandler, AZ 85225  
Phone: (480) 303-0822  
Fax: (480) 303-0824  
E-mail: admin@deiaz.com

**DEI1058  
Six Channel  
Discrete-to-Digital Interface  
Sensing 28 Volt/Ground**

**Features:**

- Senses six 28V / Ground inputs
- Small footprint (16L SOIC NB)
- Inputs are lightning protected per DO-160D Level 3
- TTL/CMOS-Compatible Tri-state outputs
- Low Cost
- -55°C to +85°C operating temperature range.
- 100% Final testing

**Functional Description:**

The DEI1058 is a six channel discrete-to-digital interface BiCMOS device. It senses six 28V/Ground discrete signals of the type commonly found in avionics systems. The inverted outputs are TTL/CMOS compatible and are enabled by the OE and CE pins. The inputs of this small 16 lead narrow body SOIC device are lightning protected to meet the requirements of DO160D waveforms 3, 4, and 5. Level 3. See figures 5-7.

interface BiCMOS device. It senses six 28V/Ground discrete signals of the type commonly found in avionics systems. The inverted outputs are TTL/CMOS compatible and are enabled by the OE and CE pins. This small 16 lead narrow body SOIC device is lightning protected to meet the requirements of DO160D waveforms 3, 4, and 5.

**Not Recommended for New Designs**

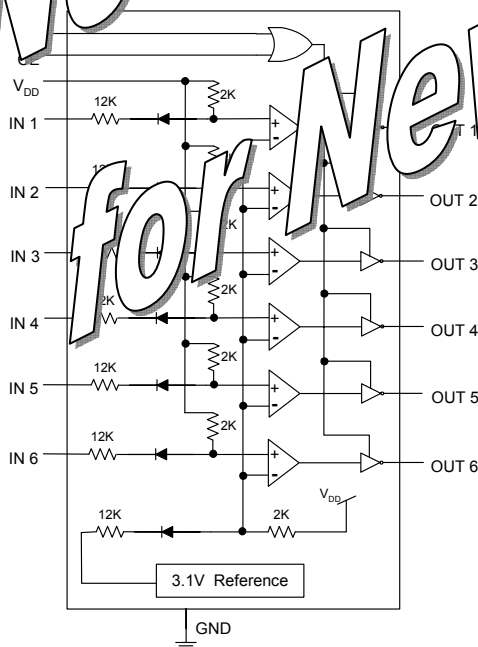


Figure 1: Concept Drawing

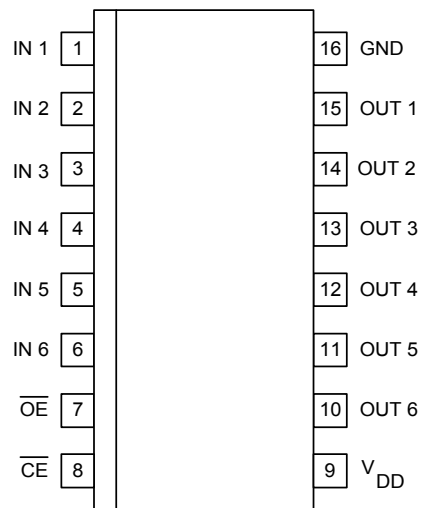


Figure 2: Pinout Diagram

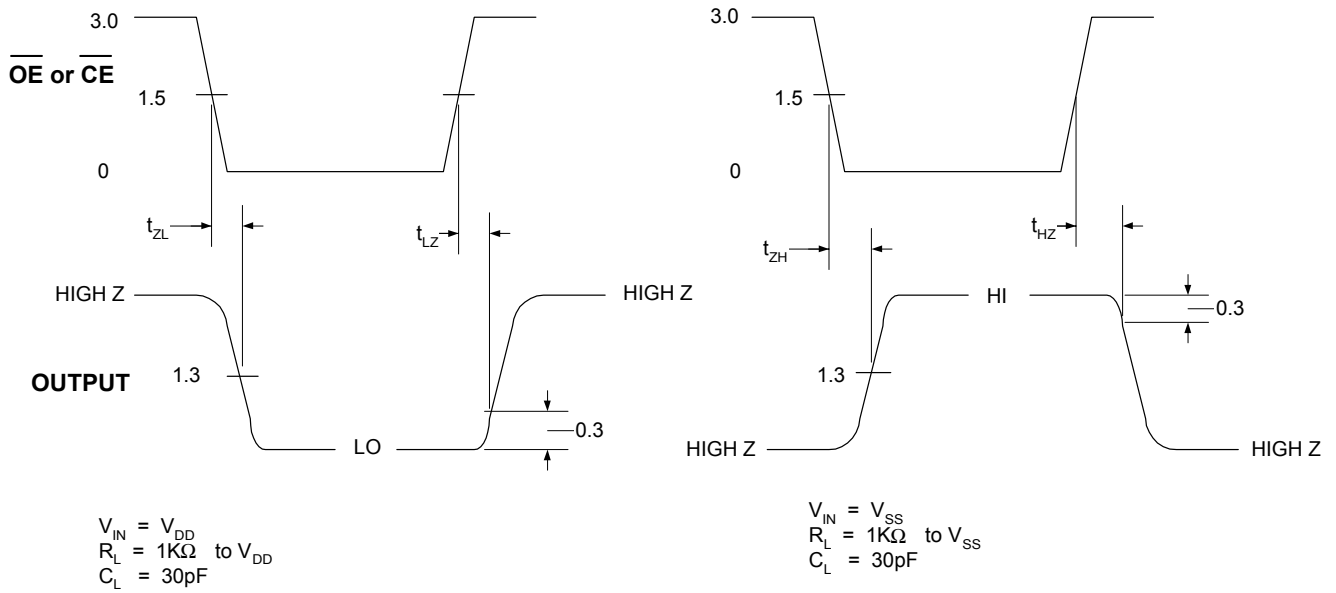
PARAMETER	MIN	MAX	UNITS
Supply Voltage $V_{DD}$	-0.3	7.0	V
Discrete Input Voltage (Pins 1-6)	-5	+35 *	V
Digital Input Voltage ( $\overline{CE}$ and $\overline{OE}$ )	$V_{SS} - 0.3$	$V_{DD} + 0.3$	V
Lightning Protection (Pins 1-6) DO160D, Waveform 3; Level 3 DO160D, Waveforms 4, and 5; Level 3	-600 -300	+600 +300	V
Storage Temperature	-55	125	°C
Operating Free Air Temperature	-55	85	°C
Lead Soldering Temperature (10 Seconds Max)	-	280	°C
Body Soldering Temperature (10 Seconds Max)	-	210	°C
The DEI1058 contains circuitry to protect inputs from damage due to electrostatic discharge. It has been characterized per JEDEC A114-A Human Body Model to Class 1. Observe precautions for handling and storing Electrostatic Sensitive Devices.			
* The DEI1058 will withstand the transient surge DC voltage step function loci limits for category B equipment per MIL-STD-704A.			

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	$V_{DD}$		4.5	5.0	5.5	V
Free Air Operating Temp.	$T_A$	$V_{DD} = 4.5 - 5.5$ V	-55		85	°C
Logic Output Sink Current	$I_{OL}$	$V_{DD} = 4.5 - 5.5$ V			5.0	mA
Logic Output Source Current	$I_{OH}$	$V_{DD} = 4.5 - 5.5$ V	-5.0			mA

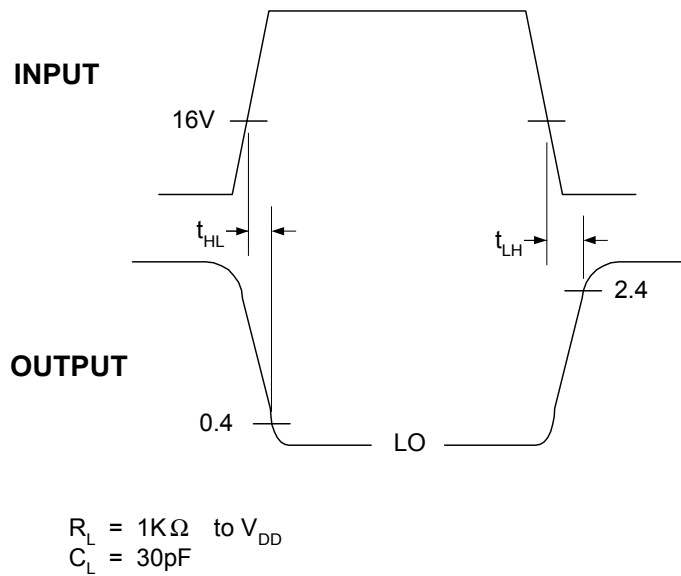
$\overline{CE}$ (Chip Enable)	$\overline{OE}$ (Output Enable)	Discrete Input	Output
0	0	28V	0
0	0	Ground	1
1	X	X	High Z
X	1	X	High Z

**Table 4: DE11058 Electrical Characteristics**  
 (T<sub>A</sub> = -55°C TO +85°C, V<sub>DD</sub> = 4.5 TO 5.5 V, Unless otherwise noted)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
<b>Power Supply and Thermal Data</b>						
Supply Current	I <sub>DD</sub>	V <sub>IN</sub> = V <sub>DD</sub> (all inputs) V <sub>DD</sub> = 5.5 V		5	10	mA
Thermal Resistance	θ <sub>JA</sub> θ <sub>JC</sub>	Junction to Ambient Junction to Case		110 60		°C/W
Max. Junction Temperature	T <sub>Jmax</sub>	Max. Junction Temperature			125	°C
<b>Discrete Input Characteristics</b>						
28 Volt input voltage High Output	V <sub>SG</sub>	Voltage source from input terminal to ground for Logic High Output.			3.0	V
28 Volt input voltage Low Output	V <sub>SO</sub>	Voltage source from input terminal to ground for Logic Low Output.	3.5			V
Ground State Input Resistor	R <sub>IG</sub>	Resistor from input to Ground to guarantee Logic High Output.			100	Ω
Input source current	I <sub>IO</sub>	Current sourced into 100 Ohm resistor to ground.	-100	-330		μA
Reverse Leakage Current	I <sub>IR</sub>	V <sub>IN</sub> = 35 V, V <sub>DD</sub> = 0 V			100	μA
<b>Logic Input Characteristics</b>						
CE, OE input logic 1 level	V <sub>IH</sub>		2.0			V
CE, OE input logic 0 level	V <sub>IL</sub>				0.8	V
<b>DC Output Characteristics</b>						
Output logic 1 level (TTL)	V <sub>OH</sub>	I <sub>OH</sub> = -5 mA.	2.4			V
Output logic 0 level (TTL)	V <sub>OL</sub>	I <sub>OL</sub> = 5 mA.			0.4	V
Output logic 1 level (CMOS)	V <sub>OH</sub>	I <sub>OH</sub> = -100 μA	V <sub>DD</sub> - 50mV			V
Output logic 0 level (CMOS)	V <sub>OL</sub>	I <sub>OL</sub> = 100 μA			V <sub>SS</sub> + 50mV	V
Off-state Output Current	I <sub>OZ</sub>	OE = V <sub>DD</sub> V <sub>DD</sub> = 5.5 V V <sub>OUT</sub> = 0 or V <sub>DD</sub>			+/-10	μA
<b>Switching Characteristics</b>						
I/O propagation delay	t <sub>HL</sub> , t <sub>LH</sub>	Refer to Figure 4.			150	ns
Delay from CE or OE input (with output low) to output HI-Z	t <sub>LZ</sub>	Refer to Figure 3.			25	ns
Delay from CE or OE input (with output HI-Z) to output low	t <sub>ZL</sub>	Refer to Figure 3.			25	ns
Delay from CE or OE input (with output high) to output HI-Z	t <sub>HZ</sub>	Refer to Figure 3.			25	ns
Delay from CE or OE input (with output HI-Z) to output high	t <sub>ZH</sub>	Refer to Figure 3.			25	ns



**Figure 3: Enable to Output Propagation Delay**



**Figure 4: Input to Output Propagation Delay**

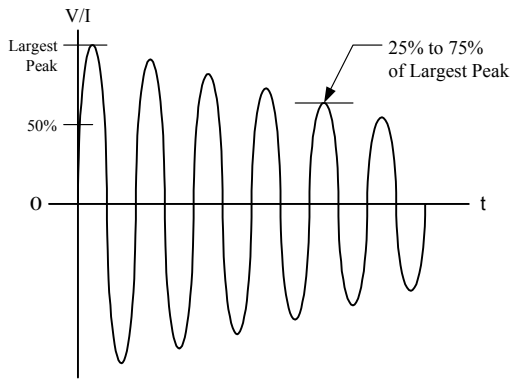


Figure 5: DO160D Voltage Waveform #3  
 $V_{OC} = 600V$ ,  $I_{SC} = 24A$ , Frequency =  $1.0MHz \pm 20\%$

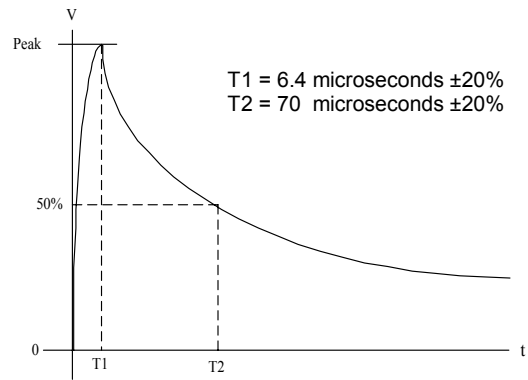


Figure 6: DO160D Voltage Waveform #4  
 $V_{OC} = 300V$ ,  $I_{SC} = 60A$   
 $T1 = 6.4 \text{ microseconds} \pm 20\%$   
 $T2 = 70 \text{ microseconds} \pm 20\%$

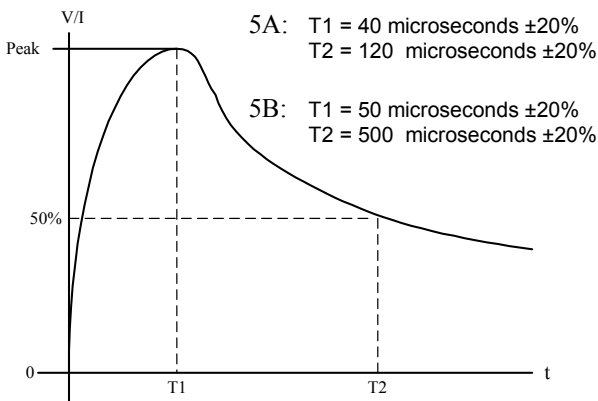


Figure 7: DO160D Voltage Waveform #5  
 $V_{OC} = 300V$ ,  $I_{SC} = 300A$

Notes:

1.  $V_{OC}$  = Peak Open Circuit Voltage available at the calibration point.
2.  $I_{SC}$  = Peak Short Circuit Current available at the calibration point.
3. Amplitude tolerances: +10%, -0%
4. The ratio of  $V_{OC}$  to  $I_{SC}$  is the generator source impedance to be used for generator calibration purposes.

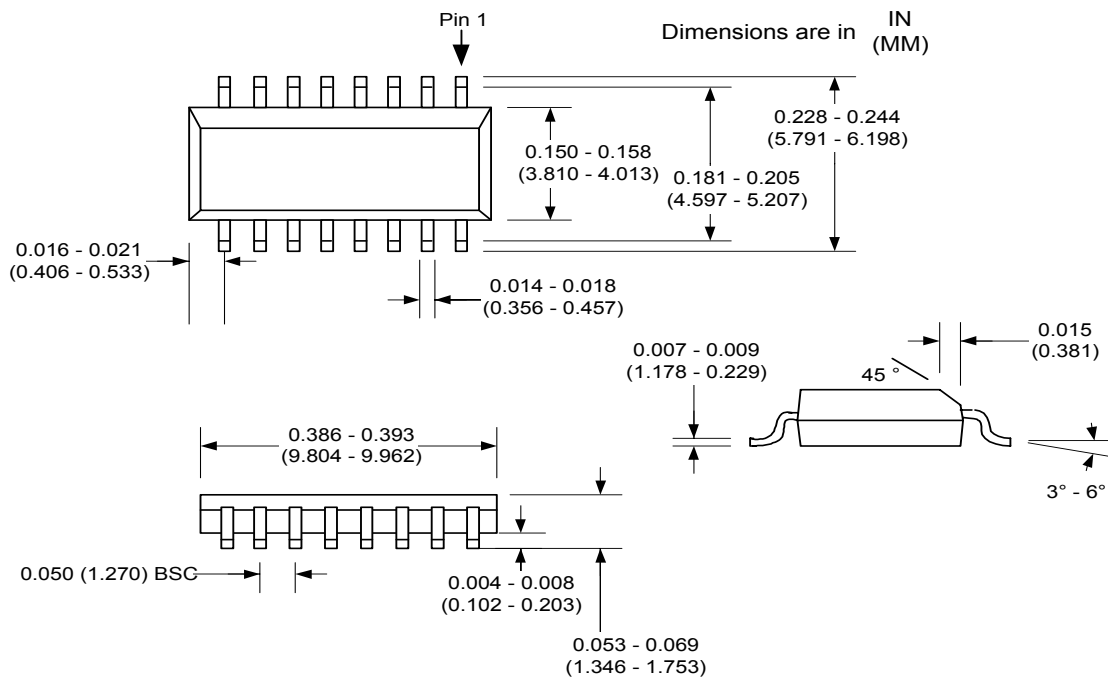


Figure 8: DE11058 Mechanical Outline  
 JEDEC MS-012-16